

# Beam Tests of Ionization Chambers for the NuMI Neutrino Beam

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**Abstract**—We have conducted tests at the Fermilab Booster of ionization chambers to be used as monitors of the NuMI neutrino beamline. The chambers were exposed to proton fluxes of up to  $10^{12}$  particles/cm<sup>2</sup>/1.56  $\mu$ s. We studied space charge effects which can reduce signal collection from the chambers at large charged particle beam intensities.

**Index Terms**—Ionization chambers, ionizing radiation, multiplication, neutrinos, particle beam measurements, space charge.

## I. INTRODUCTION

THE Neutrinos at the Main Injector (NuMI) beamline (see Fig. 1) at the Fermi National Accelerator Laboratory [1] will generate an intense  $\nu_\mu$  beam from the decays of mesons produced in the collisions of 120 GeV protons with a graphite target. The mesons are focused by magnetic “horns” into a 675 m evacuated volume to allow decays to neutrinos. A downstream aluminum/steel absorber and bedrock absorb the remnant hadrons and muons in the beam, leaving only neutrinos. The facility is expected deliver beam to neutrino experiments, beginning with the MINOS neutrino oscillation experiment, starting in early 2005.

The meson decays  $\pi/K \rightarrow \mu\nu_\mu$  produce an energetic muon for every neutrino, allowing monitoring and validation of the neutrino beam focusing to be accomplished by monitoring of the muon flux. As in several previous experiments, the muon flux and remnant hadron flux at the end of the decay volume will be measured by arrays of ionization chambers [2]–[5].

The beam monitoring system will measure the intensity and spatial distribution of the hadron beam at the end of the decay tunnel, upstream of the absorber, and of the muon beam after the absorber and at several stations in the bedrock. The monitoring system will consist of 2 m  $\times$  2 m arrays of ionization chambers with 25 cm inter-chamber spacing, with one chamber array in each of the above stations. The hadron and muon fluxes are mea-

sured of any targeting or focusing failures. The peak charged particle fluxes in one 9  $\mu$ s accelerator burst will be 2000, 25, 3, and  $1.5 \times 10^6$ /cm<sup>2</sup> in the four monitoring stations.

Each ionization chamber will measure the flux of charged particles by using an applied electric field to collect the ionization created in a helium gas volume. The charge measured from each chamber will be proportional to the charged particle flux at that location. By using an array of chambers the spatial distribution of beam intensity can be inferred. While operated without gas amplification the signal from the intense NuMI beam in one 8 cm  $\times$  8 cm ionization chamber will be 33000, 1400, 170, and 83 pC at the four stations.

The individual ionization chambers within each array are parallel plate chambers made up of two 4” square ceramic plates with Ag-Pt electrodes<sup>1</sup>. One plate has a single electrode that applies HV bias. The second plate has two electrodes: a central square sense pad measuring 3”  $\times$  3,” surrounded by a 1 cm guard ring. The sense pad is connected into the electronics which provides a virtual ground. The guard ring is grounded. The chamber gas is pure helium at atmospheric pressure.

The major limitation of ionization chambers used as beam monitors has been space charge build up inside the chamber. Intense particle fluxes release sufficient ionized charge in the chamber gas so as to create a reverse electric field inside the chamber. With the reduced net field in the chamber, ions require a longer time to reach the collection electrodes, and hence suffer more recombination loss in the gas. Recombination losses increase at larger particle fluxes, resulting in a nonlinear performance of the ionization chamber beam monitor at large intensities.

## II. BOOSTER BEAM TEST

A beam test of prototype ionization chambers was undertaken at the Fermilab Booster accelerator, which delivers up to  $10^{12}$  protons/cm<sup>2</sup> of 8 GeV in a 1.56  $\mu$ sec spill. Tested were two chambers, of 1 and 2 mm electrode spacing, with continuous gas flow. We studied the shape of the ionization versus voltage plateau curve at several intensities and the linearity of the chamber response versus beam intensity at several applied voltages.

For our beam test we placed two ionization chambers in the beamline. The chambers were housed in a stainless steel vessel with 0.005” Ti beam entrance and exit windows. Electrical feedthroughs were made with stainless steel compression fittings and PEEK plastic.

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<sup>1</sup>Manufactured by Cer-Tek, Inc., El Paso, TX.

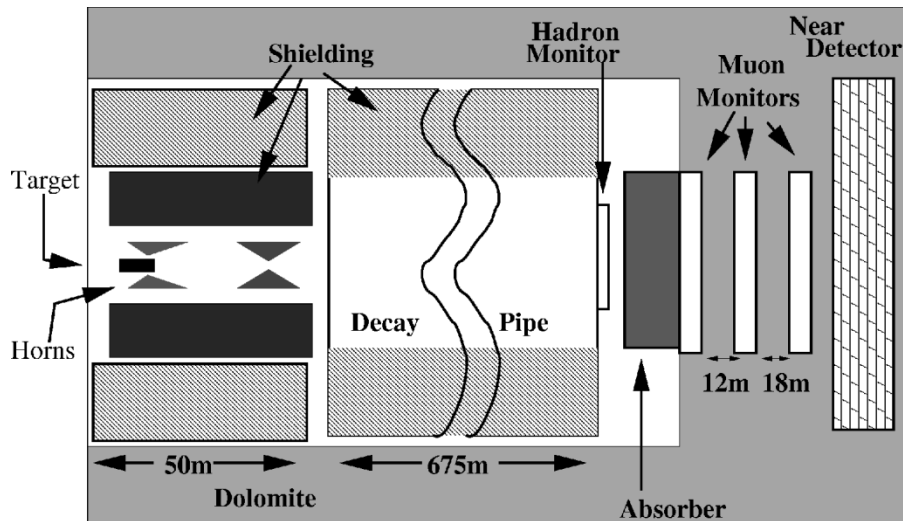


Fig. 1. Pictorial diagram of the NuMI beamline. The 120 GeV proton beam is incident on the target producing a hadron beam. The positive hadrons are focused by the horns, of which the pions travel into the decay pipe where they decay into muons and muon neutrinos, making the neutrino beam. The hadron monitor and muon monitors measure hadron and muon fluxes at their locations and are constructed of the ICs described herein.

Two gas mixtures were used in the beam test. The primary gas was pure helium supplied from a cylinder with 99.998% purity. The other gas was a mixture consisting of 98% Helium and 2% Hydrogen, with  $\leq 20$  p.p.m. of impurities. The gas was first passed through a getter and gas analyzer. Online measurement indicated impurities of  $< 1.5$  p.p.m. All gas seals were metallic consisting of compression fittings or copper gaskets compressed by vacuum fittings.

Upstream of our ion chamber (IC) vessel Fermilab provided a secondary emission monitor (SEM), to locate the beam. The SEM provided targeting information upstream of the chamber, but was not usable in the analysis because the beam diverged after passing through the SEM, and it was only capable of measuring either the horizontal or vertical profile at any given time. Furthermore, the SEM was insensitive below  $2 \times 10^{11}$  protons per pulse. During the portion of data taking above  $2 \times 10^{11}$  the SEM indicated constant spot size.

A beam toroid was the primary method of measuring the beam intensity delivered to the apparatus. The toroid was supplied with an amplifier and analog-to-digital converter (ADC) whose least significant bit was  $5 \times 10^9$  protons.

Rigidly attached on the outside of the IC vessel were two beam profile chambers fashioned out of G-10 circuit board and epoxy. Each chamber had a segmented signal electrode composed of  $1 \times 10$  cm<sup>2</sup> strips. One chamber provided the vertical profile, the other the horizontal profile. The profile chambers were the primary method for determining beam size. Gas flow was the same as that passed through the vessel. The profile chambers indicated constant beam spot size  $\sim 5$  cm<sup>2</sup>.

The signal from each of the ICs and beam profile chambers were read out into a charge integrating amplifier and then into an ADC [6]. The electronics were triggered on an accelerator clock signal shortly before the beam pulse. The charge integration time could be altered and taken between beam spills, allowing measurement of pedestals and backgrounds.

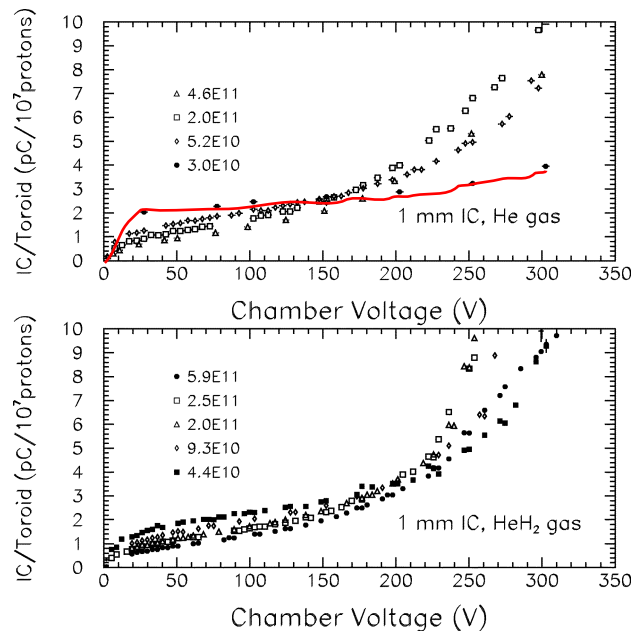


Fig. 2. High voltage scans of the 1 mm IC in Helium and Helium-Hydrogen at various beam intensities (noted in units of protons/spill). The vertical axis is the ratio of charge collected from the IC to the beam intensity measured by the toroid. Each point is the average of 10–20 beam spills.

### III. EXPERIMENTAL RESULTS

Tests of the chambers consisted of two complementary measurements. The first held the beam intensity constant, while varying the voltages applied to the chambers. The second held the applied voltages constant while adjusting the beam intensity.

The results of the first test are displayed in Figs. 2 and 3. Each chamber is exposed to several beam intensities and the voltage varied 0–350 V. The ratio of collected charge to the measured beam intensity is plotted as a function of applied voltage.

The ideal voltage plateau curve would consist of a quick rise to a constant charge collected per proton, independent of voltage

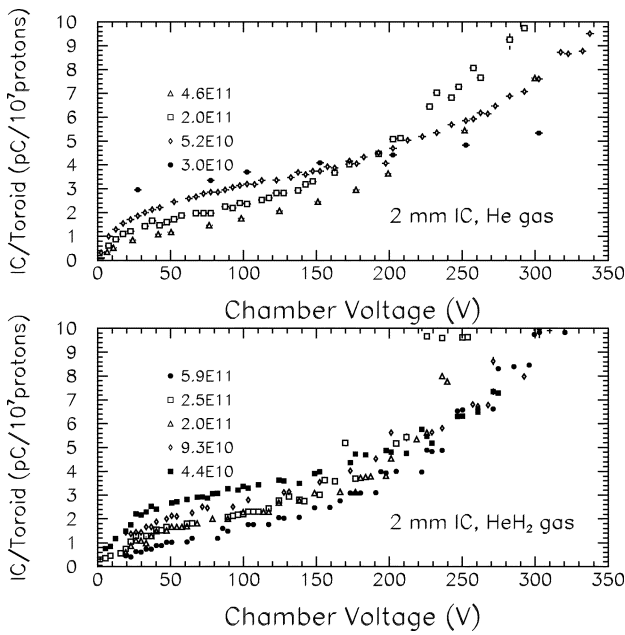


Fig. 3. High voltage scans of the 2 mm IC in Helium and Helium-Hydrogen at various beam intensities (noted in units of protons/spill). The vertical axis is the ratio of charge collected from the IC to the beam intensity measured by the toroid. Each point is the average of 10–20 beam spills.

and intensity. This constant charge collected would be equal to the amount of charge liberated in the gas per proton. At higher voltages gas amplification is expected and charge collected per proton would increase above the plateau. From the height of the plateau on the 1 mm chamber one may infer a charge ionized per proton of  $2.6 \text{ pC}/10^7 \text{ protons}$ , or 1.6 electron-ion pairs per proton incident on a 1 mm gas gap.

The drifting ions and electrons inside the chamber establish their own electric fields and the relatively slow drift velocities of the ions create a net space charge in the gas. This space charge induced electric field screens the electrodes, slowing the transit of ions and electrons across the electrode gap. As discussed extensively in [7]–[9], operating ICs at very large particle fluences modifies the voltage plateau curve discussed above. If the speed of the charges is sufficiently slowed, recombination may take place. This recombination loss is especially evident  $< 150 \text{ V}$ , where the lower voltages result in slower ion drift velocities and longer ion transit times. This loss also increases at higher beam intensity or in the larger 2 mm gap chamber, where space charge buildup should be worse.

Space charge effects were evident at all of the intensities delivered by the Booster. In Fig. 2 all of the curves, except possibly one, show a slope in the plateau region, suggesting that there is little or no region, where the charge is collected without loss or gain. The only useful voltage looks to be 130–190 V for the 1 mm chamber, where the curves all intersect.

At lower voltages the response is always greater with lesser intensity, as would be expected. At higher voltages, however, the space charge field can enhance multiplication such that it competes with recombination. The behavior at these higher voltages is complicated such that the highest gain is found at an intermediate intensity. In Section IV we provide an analysis of the competing recombination and multiplication effects in the gas.

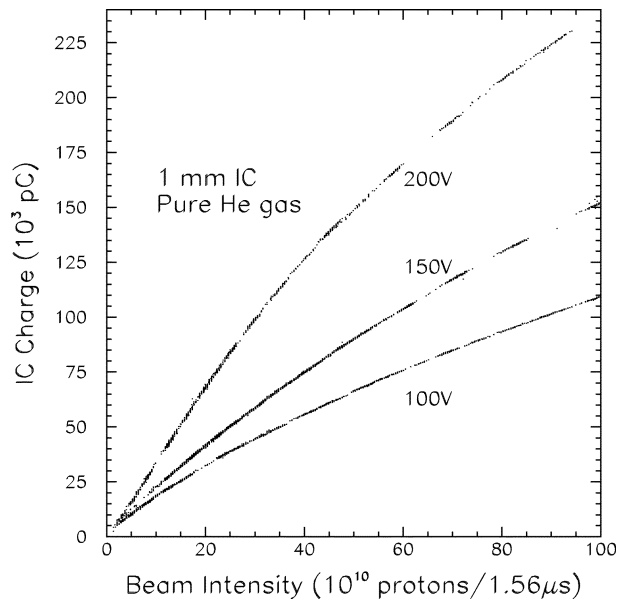


Fig. 4. Beam intensity scans of the 1 mm IC in Helium at various voltages.

Fig. 4 displays the results of the second test performed in our beam test for the case of the 1 mm chamber in Helium. The charge collected from the IC is plotted as a function of beam intensity for several applied voltages. Here, ideal curves would all join at low intensity. Recombination loss, especially visible for lower voltages, cause the curves to fall off at higher intensity. The linear region is the operating range for the chamber where charge collected is proportional to incident flux.

An analysis of the 200 V Helium curve up to  $20 \times 10^{10}$  protons/spill gives a good linear fit ( $\chi^2/N_{\text{DOF}} = 456/625$ ). However, the intercept is less than zero:  $(-0.05 \pm 0.01) \times 10^3 \text{ pC}$ . The other data could not be satisfactorily fit to a linear dependence for beam intensities  $> 10^{10}$  protons/spill.

The nonzero intercept in the 200 V data is more apparent when the curve is plotted as a ratio, as in Fig. 5 where the ratio of charge collected to beam intensity is plotted versus intensity. Here a straight line with zero intercept in the previous plot corresponds to a horizontal line. In Fig. 5, the 200 V curve is obviously curved upward then downward as the intensity is increased from 1 to  $20 \times 10^{10}$  protons/spill. This rise is responsible for the negative intercept in the linear fit. In Section IV we discuss how the interplay of multiplication and recombination can cause such an effect. Similar to the voltage plateau data, the data in Fig. 5 indicate a collected charge of  $\sim 3 \text{ pC}/10^7 \text{ protons}$  in the 1 mm chamber, or 18 electron-ion pairs per cm in the He.

The similarity between the Helium and Helium-Hydrogen data is interesting. Gas additives with lower excitation potentials are commonly used to increase the drift velocity of electrons [8], which might naively be expected to reduce recombination losses. However, the recombination loss is not substantially changed by the addition of  $\text{H}_2$ , and in Section IV we discuss how the ion drift more strongly affects space charge buildup, hence, recombination loss in the chamber.

Another parameter that might be expected to vary as a result of the additive is the ionization per proton. The incident protons excite metastable states in the Helium, which are followed by

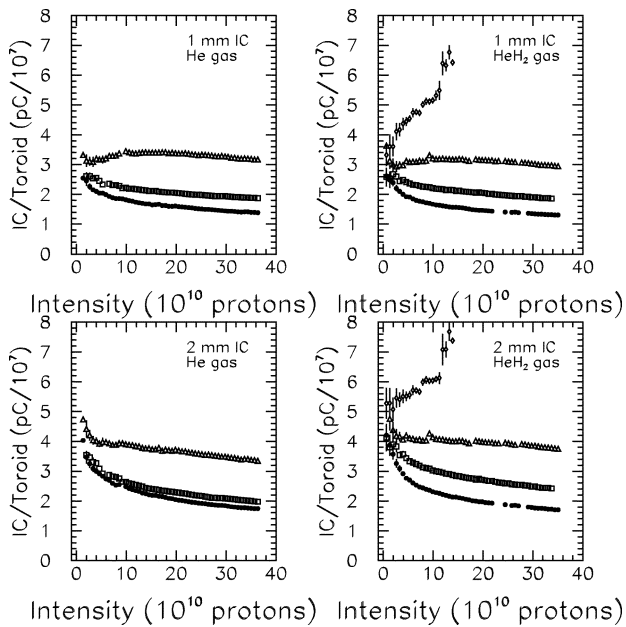


Fig. 5. Normalized beam intensity scans of 1 and 2 mm ICs at various voltages. Here, the vertical axis is the ratio of charge collected to the beam intensity as measured by the toroid. The points are for applied bias potential of 100 V  $\bullet$ , 150 V (125 V for 2 mm-He)  $\square$ , 200 V  $\triangle$ , and 250 V  $\diamond$ .

collision of Helium atoms with the  $H_2$  additive, yielding strong ionization of the  $H_2$  [10]. That the observed ionization/proton is not significantly increased by the  $H_2$  additive is perhaps indicative that even the minute impurities ( $< 1.5$  p.p.m.) in the nominally pure Helium gas are sufficient to increase the ionization. The observed 1.6–1.8 ionizations/mm per proton in our data is notably higher than the 0.8–1.0 ionizations/mm inferred from the  $dE/dx$  of fast charged particles and the  $w = 42$  eV/ionization [11] for the purest Helium. Thus, the nominally pure Helium used in typical chamber applications is likely effectively doped.

#### IV. SIMULATION

In this section, we model the data collected at the Booster beam test using a computer simulation of the pulse development in an IC. The simulation incorporates the known drift of electrons and of Helium ions in electric fields, the effects of volume recombination of charges, and of gas amplification. The simulation follows the charges during and after the beam spill, recording the net charge collected at the chamber electrodes. The simulations indicate a complex interplay between gas amplification and charge recombination as a result of space charge build up. This calculation will then be used to extrapolate to the particle fluxes and 8.6  $\mu$ s spill duration expected in NuMI. Only Helium gas was simulated as literature data for the gas properties of Helium–Hydrogen are minimal, and the beam test data were not significantly different for the two gases

##### A. Simulation Method

The differential equations governing the charge flux and electric field evolution inside the IC are nonlinear. Some earlier work analyzed special cases. [12] demonstrated that space charge accumulation in a continuously-ionized chamber

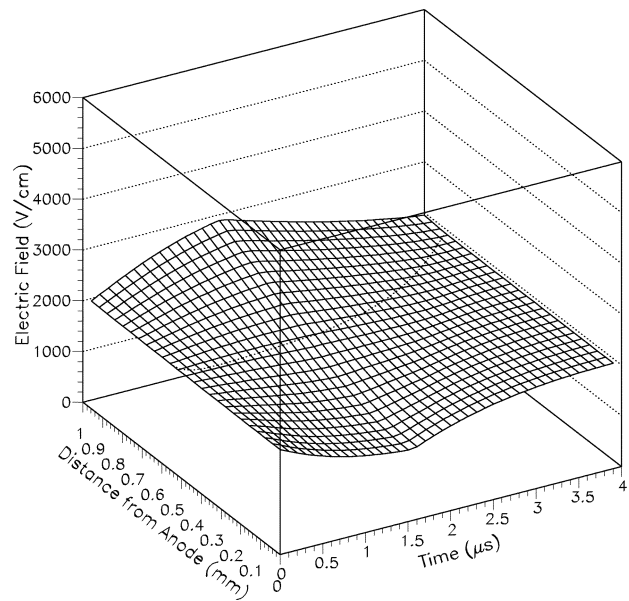


Fig. 6. Simulated electric field evolution in terms of position and time for a 1 mm IC operated at 200 V with ionization of  $10^{10}$  ion./cc/ $\mu$ s for 1.6  $\mu$ s. Small electric field disruptions due to space charge accumulation occur as the beam pulse develops.

causes the formation of a “dead region” of no electric field, and makes the approximation that all charges in the dead region are lost due to recombination. In [13], an IC ionized over a short duration is studied, but again the assumption is made that all charges in the dead zone are lost to recombination. That assumption is not valid for our experiment where the beam pulse is of short duration allowing the dead zone to disappear before the charge completely recombines.

The present work considers the time dependant case where ionization is delivered in a short pulse of 1.6  $\mu$ s and allowed to drift out of the chamber. Our simulation is a finite element calculation of one spatial dimension, such that there are series of infinite planes of charge between the electrodes. The electrons and ions are drifted with the velocities discussed in Section IV-B. Space charge is calculated at each step and an image charge is induced such that the potential difference between the electrodes is maintained at the applied voltage.

Simulated electric field distributions as a function of time are shown in Figs. 6–8. The figures show the field development using only the charge transport, and ignore charge recombination or multiplication.

The electric field simulated in Fig. 6 is calculated at an intensity of  $10^{10}$  ionizations/cm<sup>3</sup>/ $\mu$ s, where the excess of ions slightly warps the field. In Fig. 7, the ion excess is much greater, to the point where it entirely screens the anode from the applied field, creating a dead zone. As ionization continues in the dead zone the ion and electron densities there increase because the charges are effectively trapped. When the beam spill ends the dead zone slowly fades away. Charge is able to escape from the edge of the dead zone because the dead zone is not created by the charge inside, but the excess of ions outside of it.

Fig. 8 is calculated at the same intensity as Fig. 7, but for the 2 mm gap chamber. The half of the chamber close to the cathode has almost exactly the behavior of the 1 mm case. This

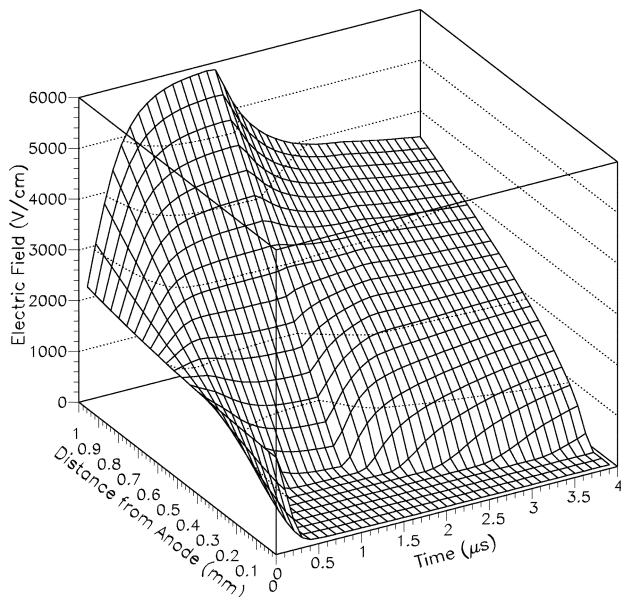


Fig. 7. Simulated electric field evolution in terms of position and time for a 1 mm IC operated at 200 V with ionization of  $10^{11}$  ion./cc/ $\mu$ s for 1.6  $\mu$ s. A “dead zone” region with a very low electric field forms at about 0.3  $\mu$ s into the beam spill, and eventually grows to cover a third of the chamber. The space charge accumulation also increases the electric field in part of the chamber to the point where the maximum electric field at the cathode is almost three times the applied electric field.

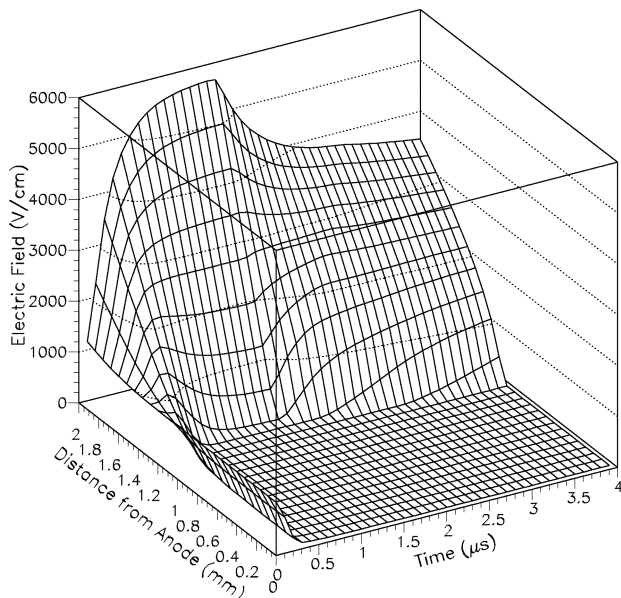


Fig. 8. Simulated electric field evolution in terms of position and time for a 2 mm IC operated at 200 V with ionization of  $10^{11}$  ion./cc/ $\mu$ s for 1.6  $\mu$ s. A “dead zone” region with a very low electric field forms at about 0.3  $\mu$ s into the beam spill, and eventually grows to cover most of the chamber. Shortly into the spill, the behavior of the half of the chamber adjacent to the cathode is almost identical to that of the 1 mm chamber in Fig. 7.

similarity is a result of the complete screening of the electric field by space charge which makes the rest of the chamber in the dead zone irrelevant, until the charge has a chance to escape after the ionization period (the beam spill) ends.

### B. Gas Properties

The parameters of charge drift, loss, and amplification used in this simulation have been taken from several literature sources. The electron drift velocities as a function of electric field are

taken from [14]. For the drift of Helium, we use the mobility for the  $\text{He}_2^+$  ion,  $\mu_{\text{He}_2^+} = 20 \text{ cm}^2/(\text{V} \cdot \text{s})$  [14], following the discussion of [10] which notes that above pressures of a few Torr,  $\text{He}^+$  ions tend to collide in the gas and form molecular ions. Previous work [15], [16] have cited the  $\text{He}^+$  ion’s mobility of  $10 \text{ cm}^2/(\text{V} \cdot \text{s})$  as the relevant mobility for He.

We simulated charge loss through two- and three-body volume recombination of electrons ions. [14] and [17] parameterize recombination of the form:  $dn_-/dt = dn_+/dt = -rn_-n_+$ , with  $n_+$  ( $n_-$ ) the positive (negative) ion densities in the gas, and the measured recombination coefficient  $r = 2.4 \times 10^{-8} \text{ cm}^3/(\text{ion} \cdot \text{s})$ .

We did not simulate charge loss through the process of electron attachment to electronegative impurities and subsequent recombination. Using the data from [7] and [17] we find that the attachment of electrons to Oxygen in the gas is insignificant for impurity levels less than 30 p.p.m. (to be compared with  $< 1.5$  p.p.m. observed in our chambers). Attachment is negligible over the drift region and occurs primarily in the dead zone where the electrons persist for a greater time. There, the electrons will attach with a time constant  $\tau = (67/x) \text{ ms}$ , where  $x$  is the impurity level in p.p.m. The electrons persist in the dead zone time of order 10  $\mu$ s and the impurities in our beam test were of order 1 p.p.m giving about 0.1% attachment.

Charge amplification in the chamber gas is modeled via  $dN/dx = N\alpha$ , with the Townsend coefficient  $\alpha$  modeled via  $\alpha/P = A \exp[-B/(X/P)]$ , where  $P$  is the chamber gas pressure,  $X$  is the applied electric field, and the parameters  $A = 3 \text{ ion pairs}/(\text{cm} - \text{Torr})$  and  $B = 25 \text{ V}/(\text{cm} - \text{Torr})$  [18]. This parameterization is taken from a source with similar gas purity, which is of importance because the purest Helium gas has significantly lower Townsend coefficient but is sensitive to even a few parts per billion impurity level [14].

The ionization rate in the simulation is quoted in units of ionizations/ $\text{cm}^3/\mu$ s in order to factor out the question of how many ionizations are created by an incident proton. Given  $dE/dx$  and  $W$ , the average energy loss necessary to create one ionization in the gas, for Helium, values of 8–16/cm have been derived [11], [15], [16], [19], but this too is sensitive to impurity level. For comparison to our data from the Booster beamtest, 1 ion./cc/ $\mu$ s corresponds to 0.6 protons/spill if the beam spot size of  $5 \text{ cm}^2$  and  $\sim 16$  ionizations/cm in Helium are used.

### C. Simulation Results

We found that the simulated space charge accumulation causes not only recombination losses, but the high fields also cause significant multiplication. This result can be seen in Figs. 9 and 10 where the charge collected per ionization can actually increase with ionization, until recombination takes over. This should be compared to Fig. 5. Both the data and the simulation indicate such an effect. This feature of the curve makes the fit line have a negative intercept, as stated earlier. The lower voltage required in the simulation to generate this effect suggests that multiplication may be overstated in simulation.

The simulation was used to generate voltage plateau curves as well. The results, shown in Figs. 11 and 12, can be compared to Figs. 2 and 3, respectively. The behavior is marked by greater losses at high intensity and low voltage, and also by a crossing

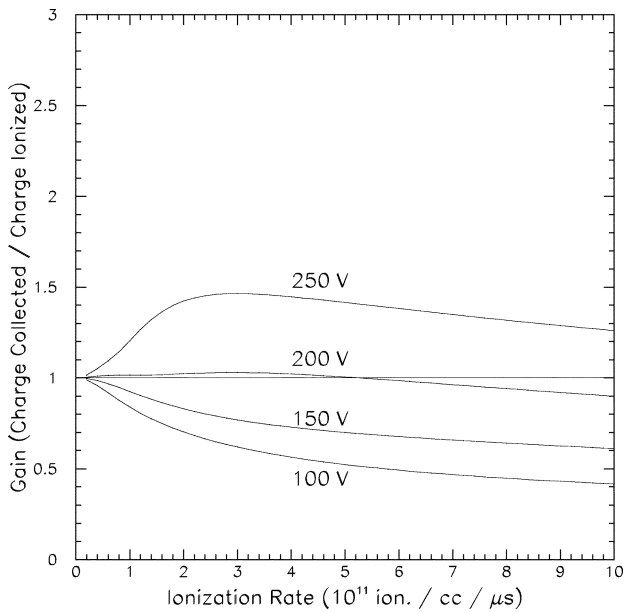


Fig. 9. Simulated normalized intensity scans of a 1 mm chamber operated at various voltages where charge recombination and gas multiplication are included. The vertical axis is the ratio of charge collected to the amount of charge initially ionized in the chamber. The horizontal line at 1.0 on the vertical axis is expected when the space charge effects of recombination and multiplication are ignored.

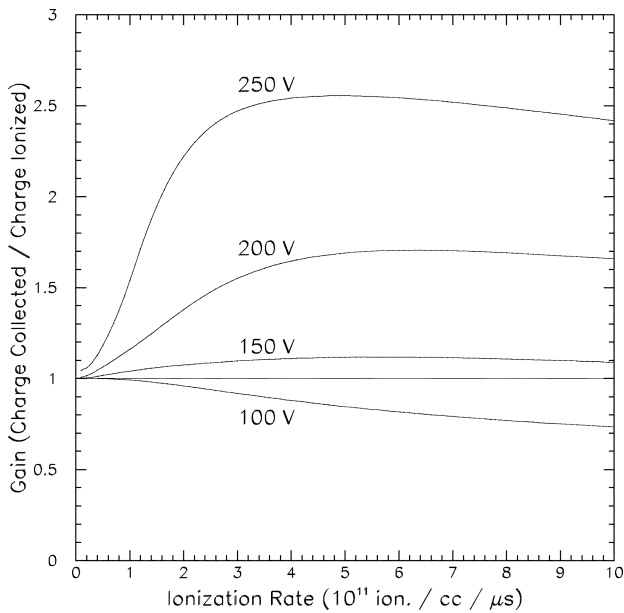


Fig. 10. Simulated normalized intensity scans of a 2 mm chamber operated at various voltages where charge recombination and gas multiplication are included. The vertical axis is the ratio of charge collected to the amount of charge initially ionized in the chamber. The horizontal line at 1.0 on the vertical axis is expected when the space charge effects of recombination and multiplication are ignored.

point where the curves all approach each other. The crossing point occurs when the charge collected equals the charge liberated in the gas. In the simulation this occurs at  $\approx 140$  V and 210 V for the 1 and 2 mm chambers. In the data, these points occur at 175 V and 190 V. Another feature is that higher intensities can show gain at lower voltages, resulting in the curves diverging after the crossing point.

comparison of data and sim

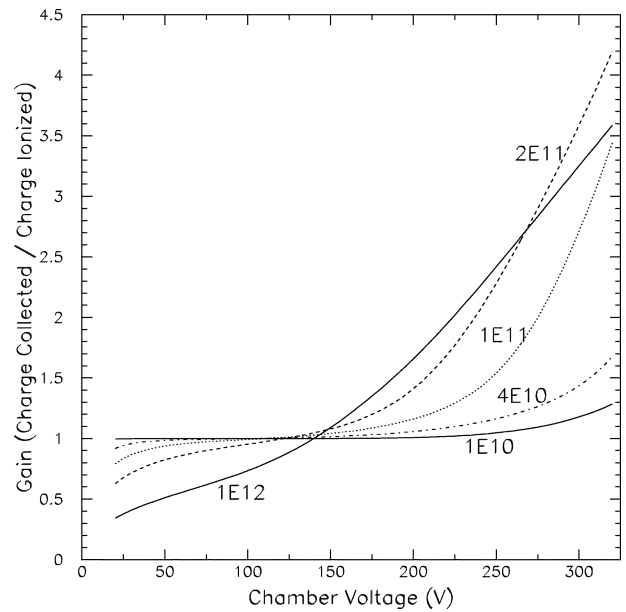


Fig. 11. Simulated voltage scans of a 1 mm IC operated at various intensities where charge recombination and gas multiplication are included. The vertical axis is the ratio of charge collected to the amount of charge initially ionized in the chamber.

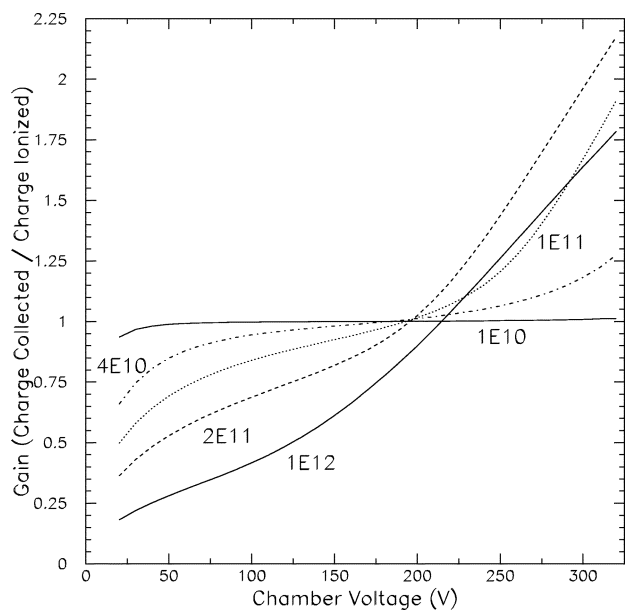


Fig. 12. Simulated voltage scans of a 2 mm IC operated at various intensities where charge recombination and gas multiplication are included. The vertical axis is the ratio of charge collected to the amount of charge initially ionized in the chamber.

The behavior observed in the data is nominally reproduced by the simulation. The crossing point occurs at a higher voltage than in the simulation of the 1 mm chamber, again suggesting that multiplication is overstated there. The crossing point can be moved left and right by simply changing the value of the Townsend coefficient  $\alpha$  and is particularly sensitive to the parameter  $B$ . Hence, the data can constrain the value of  $\alpha$  and possibly the recombination coefficient  $r$ .

## V. CONCLUSION

We have performed a beam test of Helium- and Helium–Hydrogen-filled ionization chambers at the Fermilab Booster accelerator. We have compared the experimental results to our own calculation of the expected charge collection in such chambers. While we have yet to extrapolate our calculations to the anticipated NuMI beam environment using the constraints of our beam test data, several effects of interest are observed. First, calculation of the expected ionization per charged particle in Helium based on  $dE/dx$  loss and the value  $w = 42$  eV from [11] may ignore  $\sim$  p.p.m. impurities in most chamber gas which result in additional ionization. Second, similar to previous work, our results indicate that space charge effects induce recombination losses of the collected charge at high particle fluxes; however, our results indicate additionally that gas amplification occurs in the ICs at high beam intensities due to the large space charge buildup of the electric field. The gas amplification gains compete with the losses due to recombination, effectively extending the range of linear response of the IC with respect to beam intensity.

A possible method of ameliorating the space charge effects would be to reduce the gas pressure, thus, proportionally reducing the gas ionized. However, the onset of multiplication would occur at a correspondingly lower voltage. This would require the maximum applied voltage to also be proportionally reduced with the pressure. These effects somewhat offset each other, minimizing any gains from operating at lower pressure.

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## REFERENCES

- [1] J. Hylen *et al.*, “Conceptual Design for the Technical Components of the Neutrino Beam for the Main Injector (NuMI),” Fermilab, TM-2018, 1997.
- [2] R. Blair *et al.*, “Monitoring and calibration system for neutrino flux measurement in a high energy dichromatic beam,” *Nucl. Instrum. Methods*, vol. A226, p. 281, 1984.
- [3] A. A. Belkov, A. P. Bugorsky, V. I. Kurbakov, A. I. Mukhin, and Y. M. Sviridov, “Absolute calibration of muon detectors for IHEP neutrino beam monitoring system,” .
- [4] J. E. Hill *et al.*, “Tests of beam monitoring equipment for a neutrino experiment,” *Int. J. Mod. Phys.*, vol. A16S1B, pp. 758–760, 2001.
- [5] H. Wachsmuth, “Neutrino beam monitoring,” in *Proc. Symp. Beam Intensity Measurement*, Daresbury, U.K., 1968, DNPL/RI, pp. 68–74.
- [6] W. Kissel, B. Lublinsky, and A. Frank, “New SWIC scanner/controller system,” in *Proc. 1995 Int. Conf. Accelerator and Large Experimental Physics Control Systems*, Chicago, IL, 1996.
- [7] D. H. Wilkinson, *Ionization Chambers and Counters*. Cambridge, MA: Cambridge Univ. Press, 1950.
- [8] B. Rossi and H. Staub, *Ionization Counters and Detectors*. New York: McGraw-Hill, 1949.
- [9] G. F. Knoll, *Radiation Detection and Measurement*, 3rd ed. New York: Wiley Inc., 2000.
- [10] L. B. Loeb, *Basic Processes of Gaseous Electronics*. Berkeley, CA: Univ. California Press, 1955.
- [11] “Average Energy Required to Produce an Ion Pair,” ICRU Int. Commission Radiation Units Measurements, Washington, DC, ICRU Rep. 31, 1979.
- [12] J. W. Boag and T. Wilson, “The saturation curve at high ionization intensity,” *British J. Appl. Phys.*, vol. 3, pp. 222–229, 1952.
- [13] S. Palestini *et al.*, “Space charge in ionization detectors and the NA48 electromagnetic calorimeter,” *Nucl. Instrum. Methods A*, vol. 421, pp. 75–89, 1999.
- [14] J. Dutton, “A survey of electron swarm data,” *J. Phys. Chem. Ref. Data*, vol. 4, pp. 577–856, 1975.
- [15] F. Sauli, “Principles of operation of multiwire proportional and drift chambers,” CERN, CERN preprint CERN-77-09, 1977.
- [16] W. Blum and L. Rolandi, *Particle Detection with Drift Chambers*. Berlin, Germany: Springer-Verlag, 1994.
- [17] S. Brown, *Basic Data of Plasma Physics: The Fundamental Data on Electrical Discharges in Gases*. New York: AIP, 1994.
- [18] A. von Engel, *Ionized Gases*. New York: Springer-Verlag, 1995.
- [19] K. Hagiwara *et al.*, “Review of particle properties,” *Phys. Rev. D*, vol. 66, p. 010001, 2002.